GaAs IC 5 Bit Digital Attenuator
1 dB LSB Positive Control 0.5–2 GHz

Alpha

AA101-80

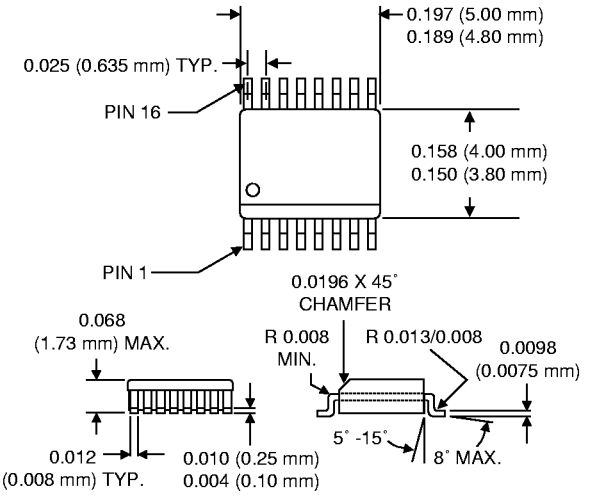
Features

- Attenuation 1 dB Steps to 31 dB with High Accuracy
- Single Positive Control (+3 to +5 V) for Each Bit
- Low DC Power Consumption
- Small Low Cost SSOP-16 Plastic Package

Description

The AA101-80 is a 5 bit, single positive control GaAs IC FET digital attenuator in a low cost SSOP-16 package. This attenuator has an LSB of 1 dB and a total attenuation of 31 dB. The attenuator requires external DC blocking capacitors, positive supply voltage (V_S) and five individual bit control voltages (V_1–V_5). The AA101-80 is particularly suited where high attenuation accuracy, low insertion loss and low intermodulation products are required. Typical applications include base station, wireless data, and wireless local loop gain level control circuits.

SSOP-16



Electrical Specifications at 25°C (0, +5 V)

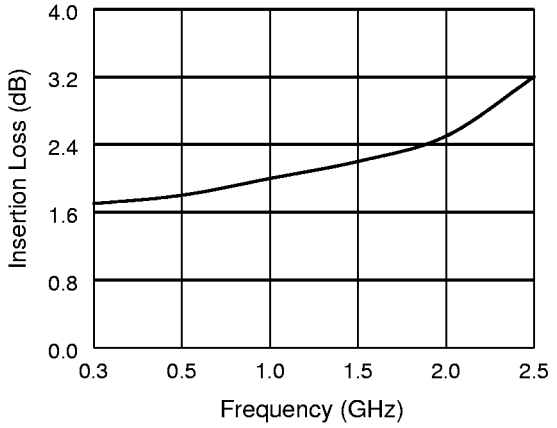
Parameter[1]	Frequency	Min.	Typ.	Max.	Unit
Insertion Loss[2]	0.5–1.0 GHz 0.5–2.0 GHz		2.0 2.6	2.4 3.1	dB dB
Attenuation Range			31		dB
Attenuation Accuracy[3]	0.5–1.0 GHz 0.5–2.0 GHz	± (0.2 + 3% of Attenuation Setting in dB) ± (0.3 + 5% of Attenuation Setting in dB)			dB dB
VSWR (I/O)[4]	0.5–2.0 GHz		1.5:1	2.0:1	

Operating Characteristics at 25°C (0, +5 V)

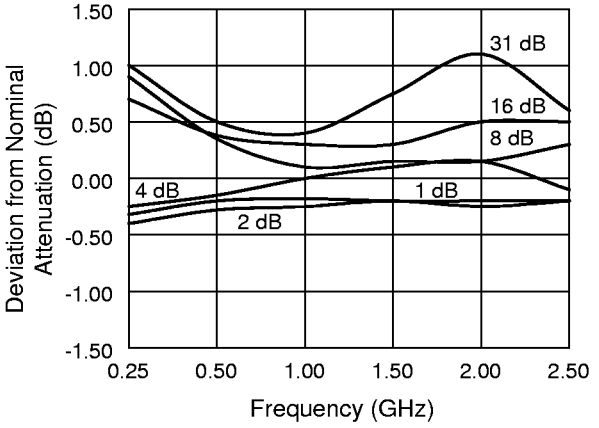
Parameter	Condition	Frequency	Min.	Typ.	Max.	Unit
Switching Characteristics[5]	Rise, Fall (10/90% or 90/10% RF) On, Off (50% CTL to 90/10% RF) Video Feedthru			150 300 70		ns ns mV
Input Power for 1 dB Compression	V_S = +3 V V_S = +5 V	0.9 GHz 0.9 GHz		+21 +27		dBm dBm
Intermodulation Intercept Point (IP3)	For Two-tone Input Power +5 dBm V_S = +3 V V_S = +5 V	 0.9 GHz 0.9 GHz		 +41 +44		 dBm dBm
Control Voltages	V_{Low} = 0 to 0.2 V @ 20 µA Max. V_{High} = +3 V @ 100 µA Max. to +5 V @ 200 µA Max. V_S = V_{High} ± 0.2 V					

1. All measurements made in a 50 Ω system, unless otherwise specified.
2. Insertion loss changes by 0.003 dB/°C.
3. Attenuation referenced to insertion loss.
4. Input/output.
5. Video feedthru measured with 1 ns risetime pulse and 500 MHz bandwidth.

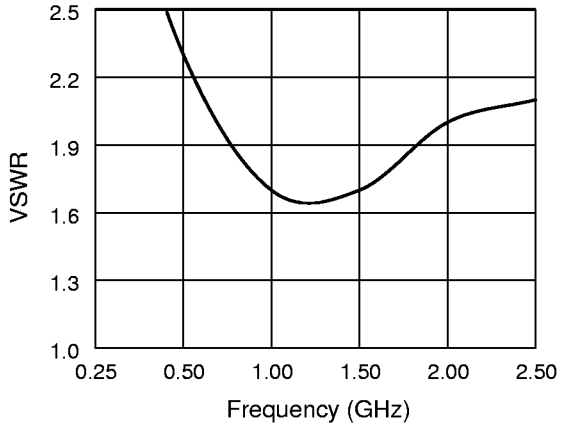
Typical Performance Data (0, +5 V)



Insertion Loss vs. Frequency



Attenuation Accuracy vs. Frequency



VSWR vs. Frequency (Worst Case)

Truth Table

V_1	V_2	V_3	V_4	V_5	Attenuation
16 dB	8 dB	4 dB	2 dB	1 dB	J_1–J_2
V_{High}	V_{High}	V_{High}	V_{High}	V_{High}	Reference I.L.
V_{High}	V_{High}	V_{High}	V_{High}	0	1 dB
V_{High}	V_{High}	V_{High}	0	V_{High}	2 dB
V_{High}	V_{High}	0	V_{High}	V_{High}	4 dB
V_{High}	0	V_{High}	V_{High}	V_{High}	8 dB
0	V_{High}	V_{High}	V_{High}	V_{High}	16 dB
0	0	0	0	0	31 dB Max. Atten.

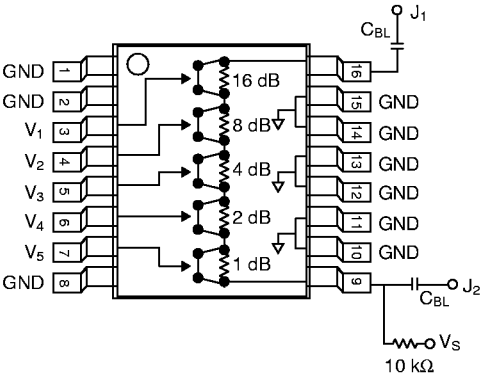
V_{High} = +3 to +5 V (V_S = V_{High} ± 0.2 V).

Absolute Maximum Ratings

Characteristic	Value
RF Input Power	1 W > 500 MHz 0/8 V 0.5 W @ 50 MHz 0/8 V
Supply Voltage	+8 V
Control Voltage	-0.2 V, +8 V
Operating Temperature	-40°C to +85°C
Storage Temperature	-65°C to +150°C

Note: Exceeding these parameters may cause irreversible damage.

Pin Out



DC blocking capacitors (C_{BL}) and biasing resistor must be supplied externally for positive voltage operation.
C_{BL} = 100 pF for operation >500 MHz.